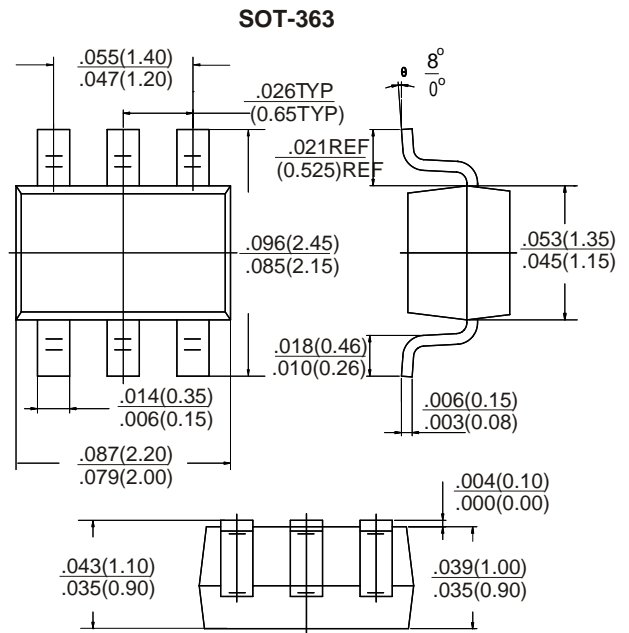
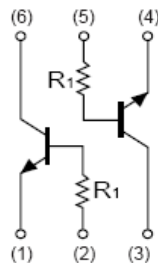


RoHS Compliant Product

## Features

- \* Two DTC144T chips in a package
- \* Transistor elements are independent, eliminating interference.
- \* Mounting cost and area can be cut in half.

## MARKING: H15



Dimensions in inches and (millimeters)

## Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{(BR)CBO}$	50	V
Collector-emitter voltage	$V_{(BR)CEO}$	50	V
Emitter-base voltage	$V_{(BR)EBO}$	5	V
Collector current	$I_C$	100	mA
Collector Power dissipation	$P_C$	150	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55~150	°C

## Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Collector-base breakdown voltage	$V_{(BR)CBO}$	50			V	$I_C=50\mu A$
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	50			V	$I_C=1mA$
Emitter-base breakdown voltage	$V_{(BR)EBO}$	5			V	$I_E=50\mu A$
Collector cut-off current	$I_{CBO}$			0.5	$\mu A$	$V_{CB}=50V$
Emitter cut-off current	$I_{EBO}$			0.5	$\mu A$	$V_{EB}=4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$			0.3	V	$I_C=10mA, I_B=1mA$
DC current transfer ratio	$h_{FE}$	100	47	600		$V_{CE}=5V, I_C=1mA$
Input resistance	$R_1$	32.9	47	61.1	K $\Omega$	
Transition frequency	$f_T$		250		MHz	$V_{CE}=10V, I_E=-5mA, f=100MHz$

**Typical Characteristics**

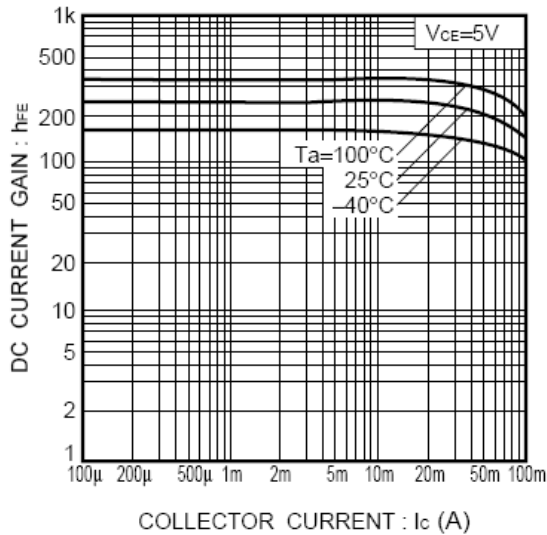


Fig.1 DC current gain vs. collector current

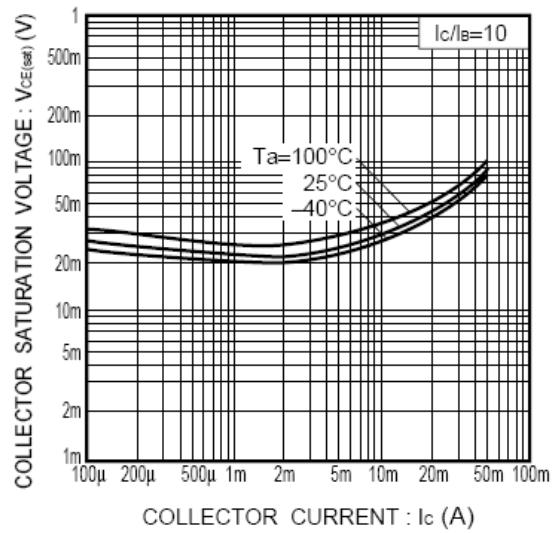


Fig.2 Collector-emitter saturation voltage vs. collector current